

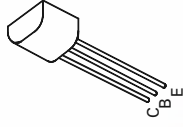
ZTX450 ZTX451

NPN SILICON PLANAR MEDIUM POWER TRANSISTORS

ISSUE 2 – MARCH 1994

FEATURES

- * 60 Volt V_{CE0}
- * 1 Amp continuous current
- * $P_{tot} = 1$ Watt



E-Line
TO92 Compatible

查询ZTX450供应商

ABSOLUTE MAXIMUM RATINGS.

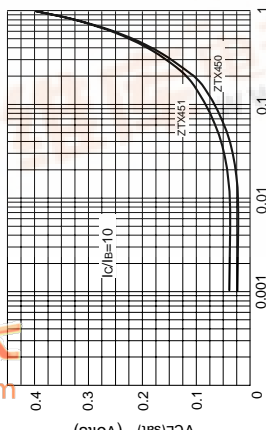
PARAMETER	SYMBOL	ZTX450	ZTX451	UNIT
Collector-Base Voltage	V_{CBO}	60	80	V
Collector-Emitter Voltage	V_{CEO}	45	60	V
Emitter-Base Voltage	V_{EBO}	5	5	V
Peak Pulse Current	I_{CM}	2	2	A
Continuous Collector Current	I_C	1	1	A
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	1	1	W
Operating and Storage Temperature Range	T_j, T_{stg}	-55 to +200		$^{\circ}C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$).

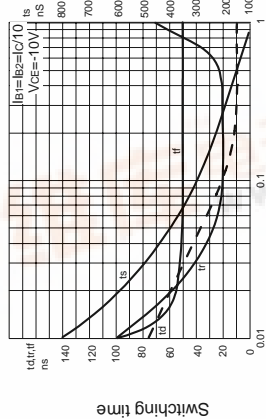
PARAMETER	SYMBOL	ZTX450		ZTX451		UNIT	CONDITIONS.
		MIN.	MAX.	MIN.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60		80		V	$I_C = 100\mu A$
Collector-Emitter Sustaining Voltage	$V_{CE0(sus)}$	45		60		V	$I_C = 10mA^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5		5		V	$I_E = 100\mu A$
Collector Cut-Off Current	I_{CBO}		0.1		0.1	μA	$V_{CB} = 45V$ $V_{CB} = 60V$
Emitter Cut-Off Current	I_{EBO}		0.1		0.1	μA	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.25		0.35	V	$I_C = 150mA, I_B = 15mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		1.1		1.1	V	$I_C = 150mA, I_B = 15mA^*$
Static Forward Current Transfer Ratio	h_{FE}	100 15	300	50 10	150		$I_C = 150mA, V_{CE} = 10V^*$ $I_C = 1A, V_{CE} = 10V^*$
Transition Frequency	f_T	150		150		MHz	$I_C = 50mA, V_{CE} = 10V$ $f = 100MHz$
Output Capacitance	C_{obo}		15		15	pF	$V_{CB} = 10V, f = 1MHz$

捷多邦, 专业PCB打样工厂, 24小时加急出货

TYPICAL CHARACTERISTICS

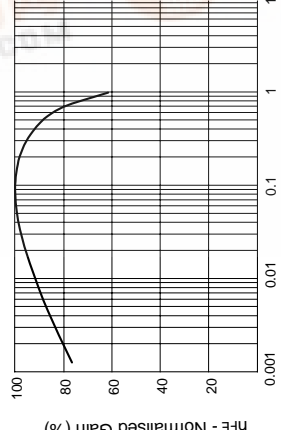


$V_{CE(sat)}$ v I_C

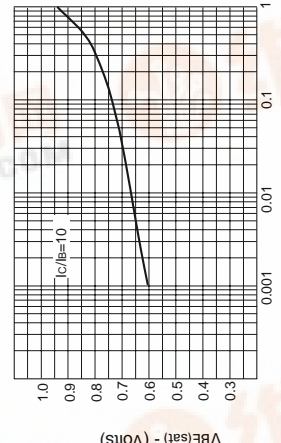


I_C - Collector Current (Amps)

Typical Switching Speeds

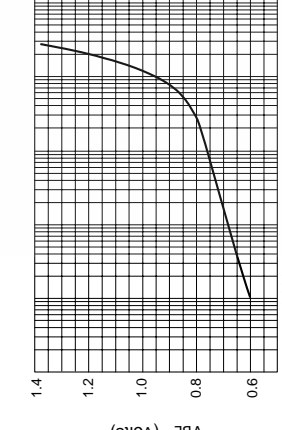


h_{FE} v I_C



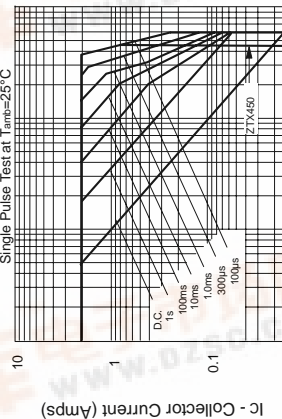
I_C - Collector Current (Amps)

VBE(sat) v I_C



I_C - Collector Current (Amps)

VBE(on) v I_C



I_C - Collector Current (Amps)

Safe Operating Area

ZTX450 ZTX451

NPN SILICON PLANAR MEDIUM POWER TRANSISTORS

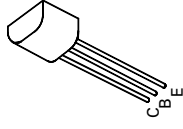
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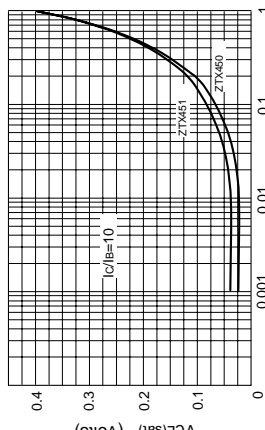
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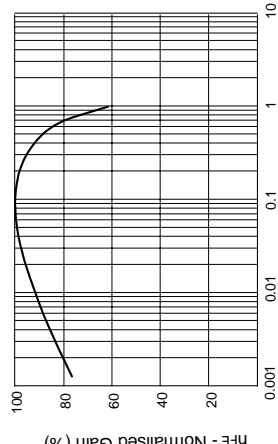
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Collector-Emitter Sustaining Voltage	$V_{CE0(sus)}$	45		60	V	$I_C=10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5		5	V	$I_E=100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		0.1		μA	$V_{CB}=45\text{V}$ $V_{CB}=60\text{V}$
Emitter Cut-Off Current	I_{EBO}		0.1		μA	$V_{EB}=4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.25		V	$I_C=150\text{mA}, I_B=15\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		1.1		V	$I_C=150\text{mA}, I_B=15\text{mA}^*$
Static Forward Current Transfer Ratio	h_{FE}	100 15	300	50 10		$I_C=150\text{mA}, V_{CE}=10\text{V}^*$ $I_C=1\text{A}, V_{CE}=10\text{V}^*$
Transition Frequency	f_T	150		150	MHz	$I_C=50\text{mA}, V_{CE}=10\text{V}$ $f=100\text{MHz}$
Output Capacitance	C_{obo}		15		pF	$V_{CB}=10\text{V}, f=1\text{MHz}$



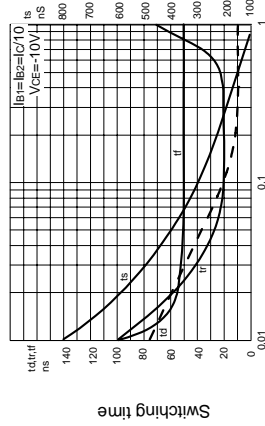
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$V_{CE(sat)}$ v I_C



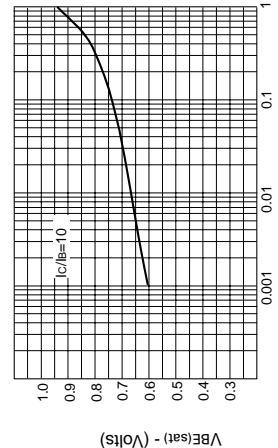
I_C - Collector Current (Amps)

h_{FE} v I_C



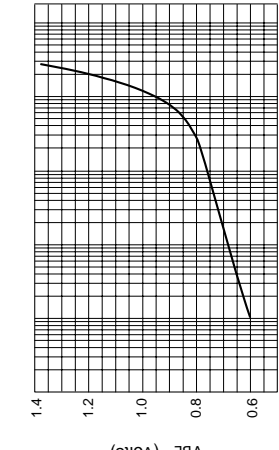
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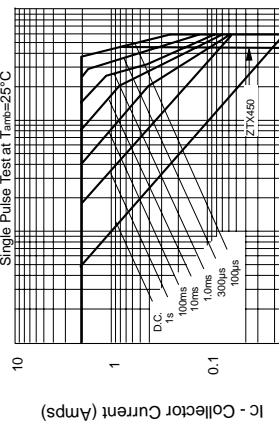
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$V_{BE(sat)}$ v I_C



I_C - Collector Current (Amps)

$V_{BE(on)}$ v I_C



I_C - Collector Current (Amps)

Safe Operating Area